

# Vorlesung 11 STM

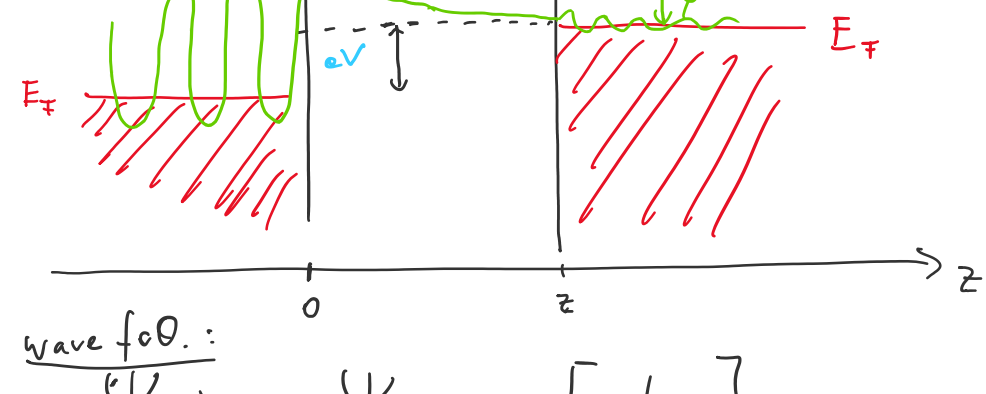
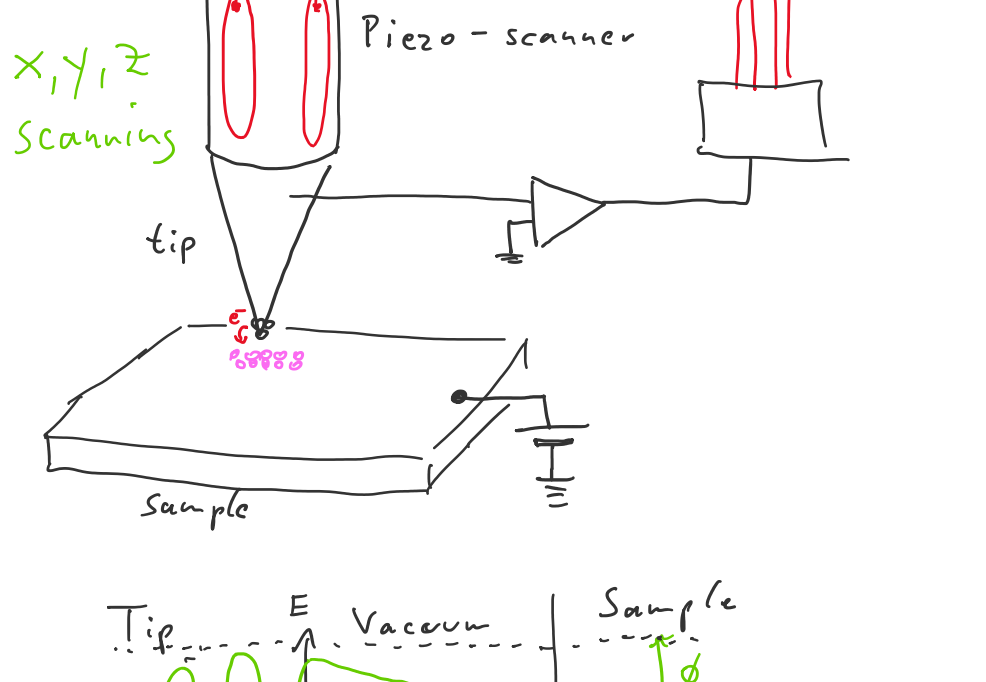
Wednesday, 13. July 2022 13:57

## 4. Spins on Surfaces (SOS)

- Molecular spin qubits:  $\oplus$  great Q-properties (spin engineering) very stable devices
- $\ominus$  no spatial information + control

Idea: Use a technique that can image molecules and allow device engineering

$\Rightarrow$  Scanning Tunneling Microscopy STM



wave fct:  $\Psi(z) = \Psi(0) \cdot \exp[-kz]$

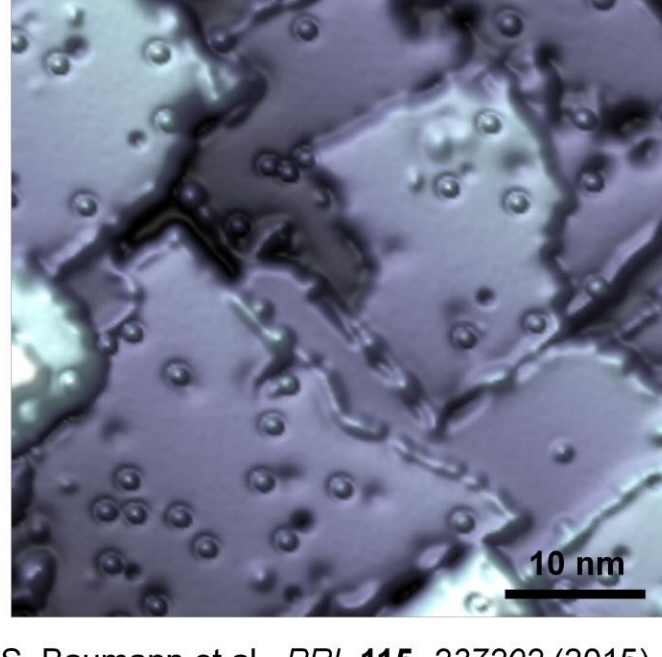
transmission  $T = \frac{I(z)}{I(0)} = \exp[-2kz]$

$k = \frac{\sqrt{2m\phi}}{\hbar}$

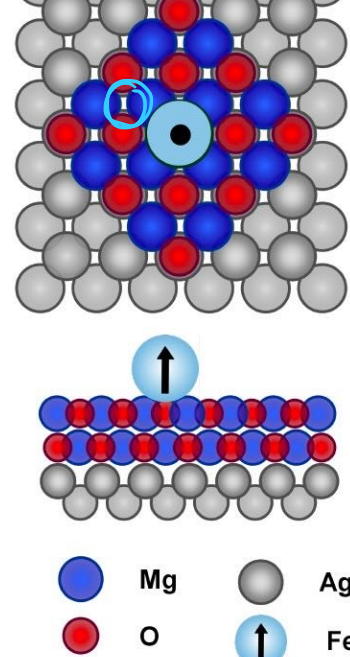
- tunnel current  $I(z)$  is very sensitive to distance  $z$

$I(z) \sim \text{pA} - \text{nA}$

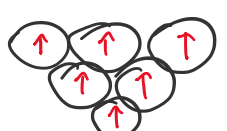
## 4.1 Local atomic spins on a surface



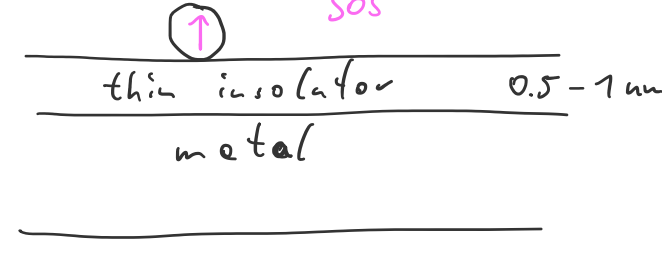
S. Baumann et al., PRL 115, 237202 (2015)



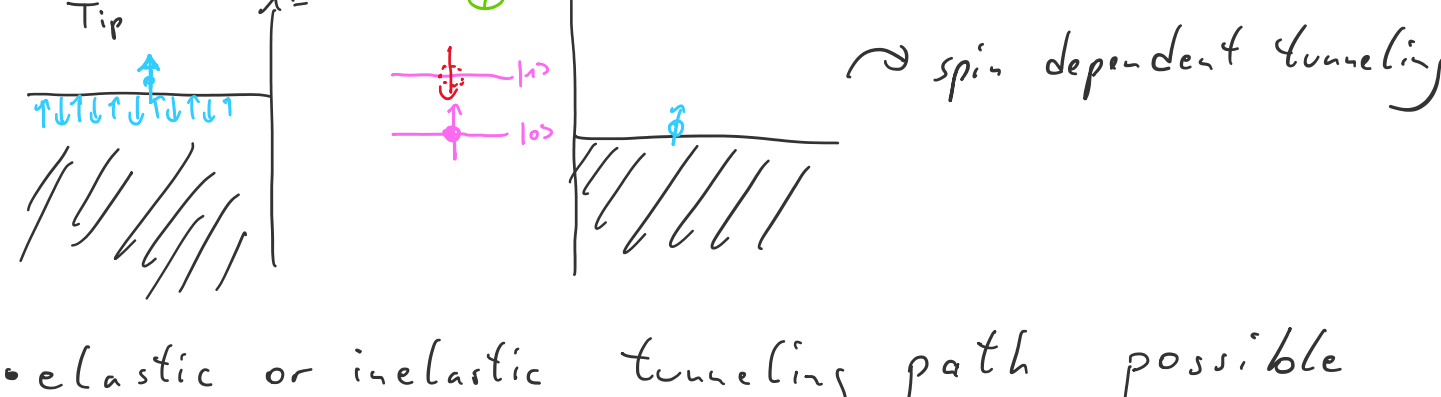
Spin sensitivity



- Insulator to decouple the SOS from strong interaction with substrate (0.5-1nm thick)



## Readout



- elastic or inelastic tunneling path possible
- $\rightarrow I$  depends on - spin of tunneling  $e^-$
- spin on the surface

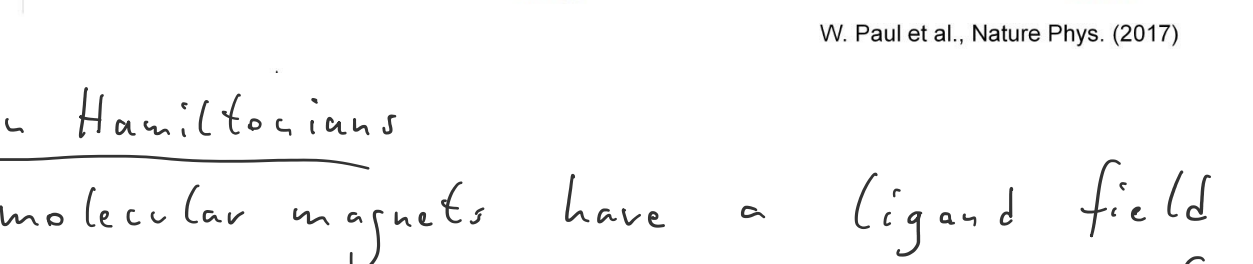
$\rightarrow$  using a magnetic tip to increase the tunneling of one spin direction

$\Rightarrow$  spin-polarized tunneling

$\Rightarrow I = g(m) \cdot V = (P_0 \sigma_0 + P_1 \sigma_1) \cdot V$

local spin  $\uparrow$  conductance of SOS 0 or 1

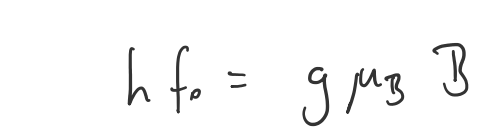
Probability of SOS in 0 or 1



W. Paul et al., Nature Phys. (2017)

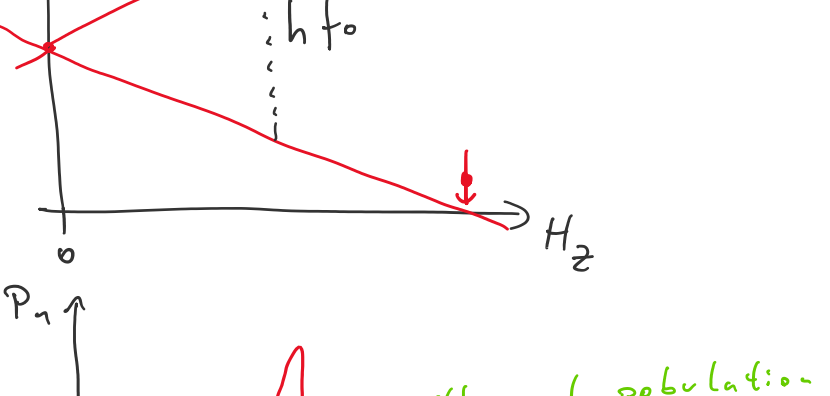
## Spin Hamiltonians

- molecular magnets have a ligand field
- atoms on surfaces see a crystal field of the surface

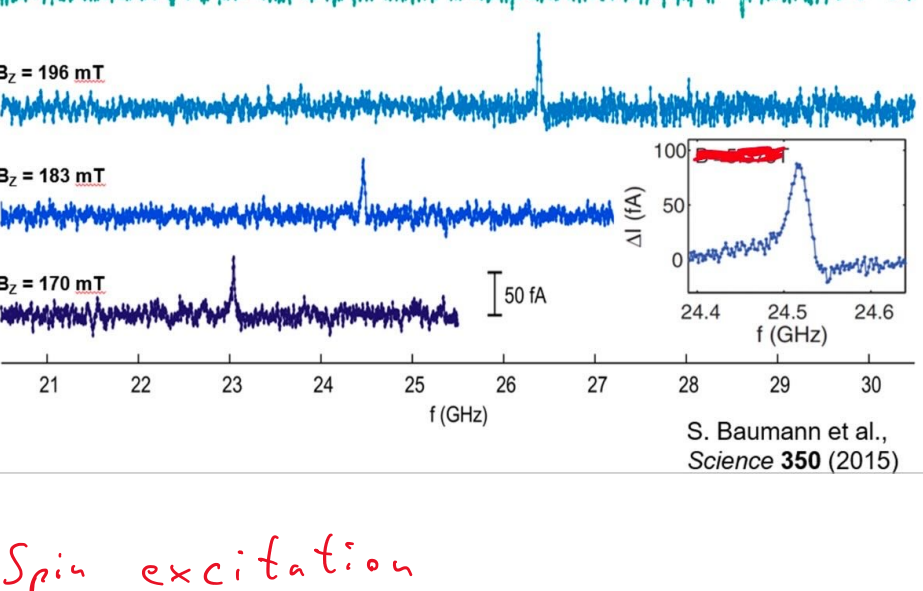


## Spin resonance

$S = \frac{1}{2}$   $hf_0 = g\mu_B B \Delta m_s \approx 2\mu_B B = 28 \frac{\text{GHz}}{\text{T}} \cdot B$

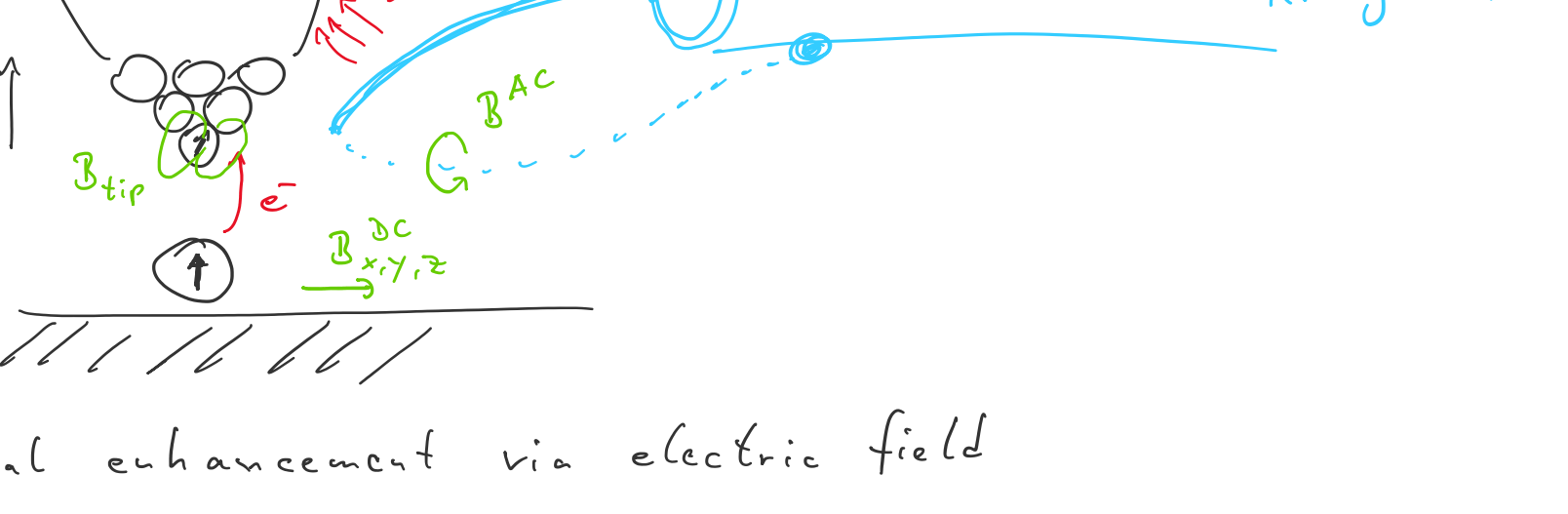


thermal population



S. Baumann et al., Science 350 (2015)

## 4.2 Spin excitation

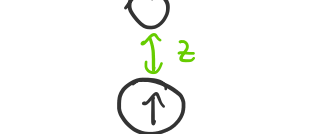


- local enhancement via electric field
- $B_{tip}$  - magnetic dipole interaction - exchange interaction

$H = J \cdot \vec{S}_{SOS} \cdot \vec{S}_{Tip} = J_0 \exp\left(-\frac{z}{d_{exchange}}\right) \cdot \vec{S}_{SOS} \cdot \vec{S}_{Tip}$

$\Delta B_{tip}(z) = \frac{\partial B_{tip}}{\partial z} \Delta z \cdot \sin(\varphi) \approx -\frac{B_{tip}}{d_{ex}} \Delta z \sin(\varphi)$

vertical displacement  $\Delta z$



electric field  $E = \frac{V}{z} (\sim 10^7 - 10^8 \frac{V}{m})$

- inhomogeneous charge distribution
- stiffness of atomic bonds

$F_{electric\ field} = F_{spring}$

$V_{RF} \sim$  shaking of atom by the electric field

$\sim$  modulation of crystal field

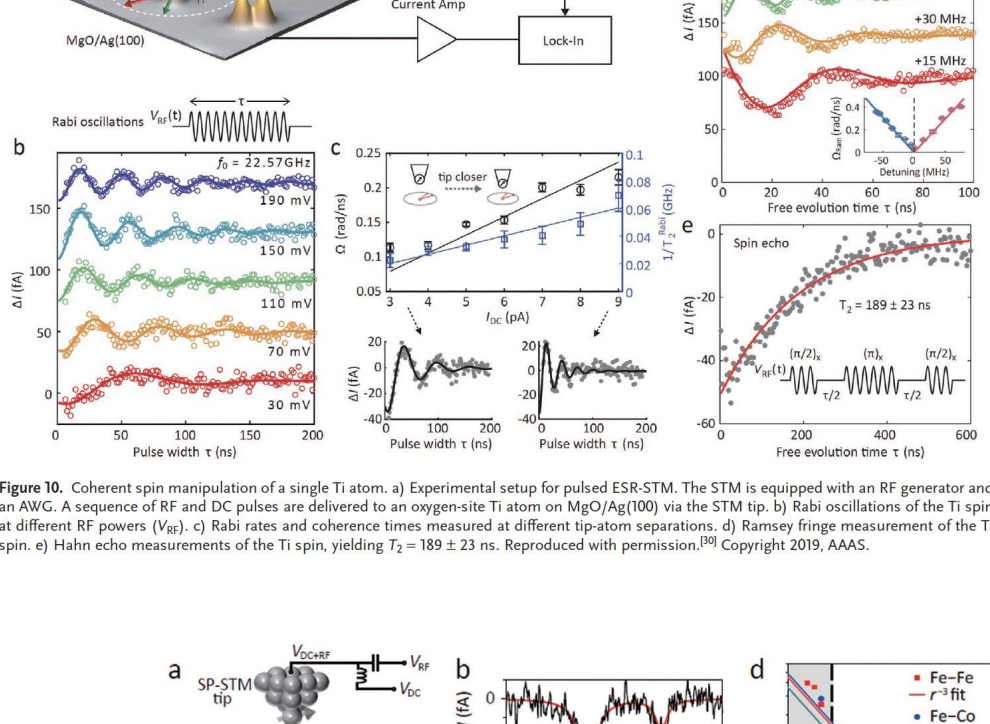


Figure 10. Coherent spin manipulation of a single Ti atom. (a) Experimental setup for pulsed ESR-STM. The STM is equipped with an RF generator and an AWG. A sequence of RF and DC pulses are delivered to an oxygen-site Ti atom on MgO(Ag100) via the STM tip. (b) STM images of the Ti atom at different RF powers. (c) Rabi rate and coherence time measured at different tip-atom separations. (d) Rabi oscillations of the Ti spin at different RF powers. (e) Hahn echo measurements of the Ti spin, yielding  $T_2 = 189 \pm 23$  ns. Reproduced with permission [10]. Copyright 2009, AAAS.

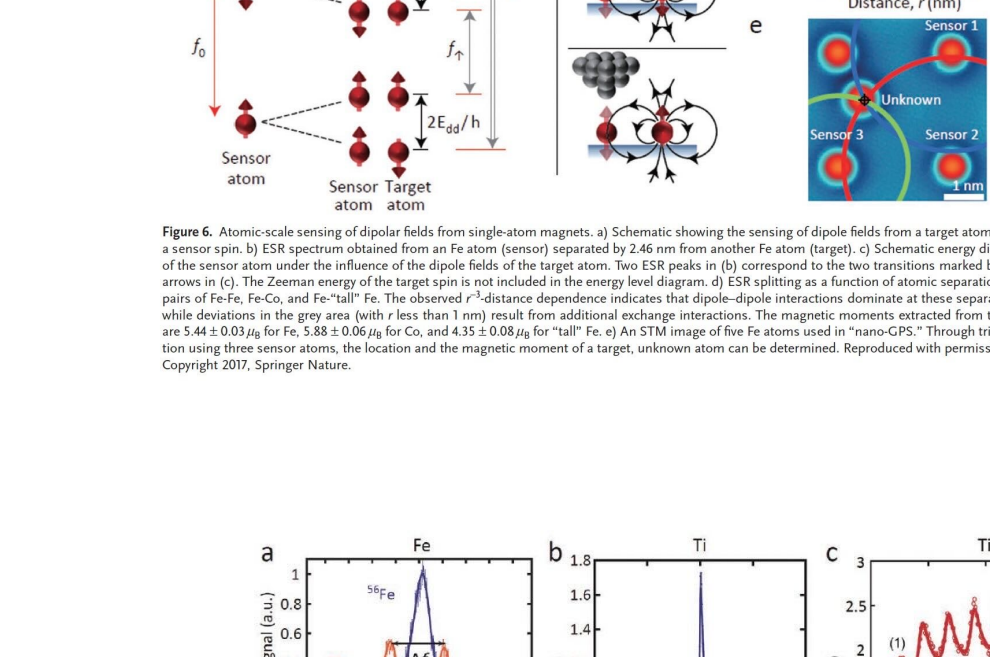


Figure 6. Atomic-scale sensing of dipolar fields. From single-atom magnets. (a) Schematic showing the sensing of dipolar fields from a target atom using a sensor spin. (b) ESR spectra of Fe atoms. (c) Binding-site-dependent ESR spectra of the same Fe atom. (d) ESR spectra of Fe atoms at different sites. (e) Schematic energy diagram of Cu.

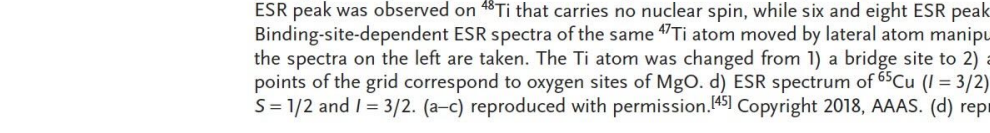


Figure 7. Hyperfine interactions of individual atoms on a surface. (a) ESR spectra measured on  $^{56}\text{Fe}$  with zero nuclear spin (blue) and  $^{57}\text{Fe}$  with  $I = 1/2$  (orange). (b) ESR spectra measured on  $^{47}\text{Ti}$  with zero nuclear spin (blue) and  $^{48}\text{Ti}$  with  $I = 3/2$  (orange). (c) ESR spectra measured on  $^{63}\text{Cu}$  with zero nuclear spin (blue) and  $^{65}\text{Cu}$  with  $I = 3/2$  (orange). (d) Schematic energy diagram of Cu.